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### Understanding **Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

#### **Details**

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	276480
Number of I/O	280
Number of Gates	1500000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	484-BGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/m1a3pe1500-1fg484">https://www.e-xfl.com/product-detail/microchip-technology/m1a3pe1500-1fg484</a>

## Temperature Grade Offerings

Package	A3PE600	A3PE1500	A3PE3000
<b>Cortex-M1 Devices</b>		<b>M1A3PE1500</b>	<b>M1A3PE3000</b>
PQ208	C, I	C, I	C, I
FG256	C, I	–	–
FG324	–	–	C, I
FG484	C, I	C, I	C, I
FG676	–	C, I	–
FG896	–	–	C, I

*Note:* C = Commercial temperature range: 0°C to 70°C ambient temperature

I = Industrial temperature range: -40°C to 85°C ambient temperature

## Speed Grade and Temperature Grade Matrix

Temperature Grade	Std.	-1	-2
C <sup>1</sup>	✓	✓	✓
I <sup>2</sup>	✓	✓	✓

*Notes:*

1. C = Commercial temperature range: 0°C to 70°C ambient temperature

2. I = Industrial temperature range: -40°C to 85°C ambient temperature

References made to ProASIC3E devices also apply to ARM-enabled ProASIC3E devices. The ARM-enabled part numbers start with M1 (Cortex-M1).

Contact your local Microsemi SoC Products Group representative for device availability:

[www.microsemi.com/index.php?option=com\\_content&id=135&lang=en&view=article](http://www.microsemi.com/index.php?option=com_content&id=135&lang=en&view=article).

**Table 2-4 • Overshoot and Undershoot Limits<sup>1</sup>**

VCCI and VMV	Average VCCI–GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle <sup>2</sup>	Maximum Overshoot/Undershoot <sup>2</sup>
2.7 V or less	10%	1.4 V
	5%	1.49 V
3 V	10%	1.1 V
	5%	1.19 V
3.3 V	10%	0.79 V
	5%	0.88 V
3.6 V	10%	0.45 V
	5%	0.54 V

**Notes:**

1. Based on reliability requirements at 85°C.
2. The duration is allowed at one out of six clock cycles. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.
3. This table does not provide PCI overshoot/undershoot limits.

## I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every ProASIC®3E device. These circuits ensure easy transition from the powered-off state to the powered-up state of the device. The many different supplies can power up in any sequence with minimized current spikes or surges. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in [Figure 2-1 on page 2-4](#).

There are five regions to consider during power-up.

ProASIC3E I/Os are activated only if ALL of the following three conditions are met:

1. VCC and VCCI are above the minimum specified trip points ([Figure 2-1 on page 2-4](#)).
2. VCCI > VCC – 0.75 V (typical)
3. Chip is in the operating mode.

**VCCI Trip Point:**

Ramping up: 0.6 V < trip\_point\_up < 1.2 V

Ramping down: 0.5 V < trip\_point\_down < 1.1 V

**VCC Trip Point:**

Ramping up: 0.6 V < trip\_point\_up < 1.1 V

Ramping down: 0.5 V < trip\_point\_down < 1 V

VCC and VCCI ramp-up trip points are about 100 mV higher than ramp-down trip points. This specifically built-in hysteresis prevents undesirable power-up oscillations and current surges. Note the following:

- During programming, I/Os become tristated and weakly pulled up to VCCI.
- JTAG supply, PLL power supplies, and charge pump VPUMP supply have no influence on I/O behavior.

## Power Calculation Methodology

This section describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in the Libero SoC software.

The power calculation methodology described below uses the following variables:

- The number of PLLs as well as the number and the frequency of each output clock generated
- The number of combinatorial and sequential cells used in the design
- The internal clock frequencies
- The number and the standard of I/O pins used in the design
- The number of RAM blocks used in the design
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in [Table 2-11 on page 2-11](#).
- Enable rates of output buffers—guidelines are provided for typical applications in [Table 2-12 on page 2-11](#).
- Read rate and write rate to the memory—guidelines are provided for typical applications in [Table 2-12 on page 2-11](#). The calculation should be repeated for each clock domain defined in the design.

### Methodology

#### Total Power Consumption— $P_{TOTAL}$

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$P_{STAT}$  is the total static power consumption.

$P_{DYN}$  is the total dynamic power consumption.

#### Total Static Power Consumption— $P_{STAT}$

$$P_{STAT} = PDC1 + N_{INPUTS} * PDC2 + N_{OUTPUTS} * PDC3$$

$N_{INPUTS}$  is the number of I/O input buffers used in the design.

$N_{OUTPUTS}$  is the number of I/O output buffers used in the design.

#### Total Dynamic Power Consumption— $P_{DYN}$

$$P_{DYN} = P_{CLOCK} + P_{S-CELL} + P_{C-CELL} + P_{NET} + P_{INPUTS} + P_{OUTPUTS} + P_{MEMORY} + P_{PLL}$$

#### Global Clock Contribution— $P_{CLOCK}$

$$P_{CLOCK} = (PAC1 + N_{SPINE} * PAC2 + N_{ROW} * PAC3 + N_{S-CELL} * PAC4) * F_{CLK}$$

$N_{SPINE}$  is the number of global spines used in the user design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the [ProASIC3E FPGA Fabric User's Guide](#).

$N_{ROW}$  is the number of VersaTile rows used in the design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the [ProASIC3E FPGA Fabric User's Guide](#).

$F_{CLK}$  is the global clock signal frequency.

$N_{S-CELL}$  is the number of VersaTiles used as sequential modules in the design.

PAC1, PAC2, PAC3, and PAC4 are device-dependent.

#### Sequential Cells Contribution— $P_{S-CELL}$

$$P_{S-CELL} = N_{S-CELL} * (PAC5 + \alpha_1 / 2 * PAC6) * F_{CLK}$$

$N_{S-CELL}$  is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

$\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in [Table 2-11 on page 2-11](#).

$F_{CLK}$  is the global clock signal frequency.

**Table 2-17 • Summary of I/O Timing Characteristics—Software Default Settings**

–2 Speed Grade, Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V,  
Worst-Case VCCI = 3.0 V

I/O Standard	Drive Strength (mA)	Equivalent Software Default Drive Strength Option) <sup>1</sup>	Slew Rate	Capacitive Load (pF)	External Resistor ( $\Omega$ )	$t_{DOUT}$ (ns)	$t_{DP}$ (ns)	$t_{DIN}$ (ns)	$t_{PY}$ (ns)	$t_{PYS}$ (ns)	$t_{EOUT}$ (ns)	$t_{ZL}$ (ns)	$t_{ZH}$ (ns)	$t_{LZ}$ (ns)	$t_{HZ}$ (ns)	$t_{ZLs}$ (ns)	$t_{ZHs}$ (ns)
3.3 V LVTT / 3.3 V LVC MOS	12	12	High	35	–	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81
3.3 V LVC MOS Wide Range <sup>2</sup>	100 $\mu\text{A}$	12	High	35	–	0.49	4.24	0.03	1.36	1.78	0.32	4.24	3.25	3.78	4.17	6.77	5.79
2.5 V LVC MOS	12	12	High	35	–	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28
1.8 V LVC MOS	12	12	High	35	–	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98
1.5 V LVC MOS	12	12	High	35	–	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37
3.3 V PCI	Per PCI spec	–	High	10	25 <sup>3</sup>	0.49	2.09	0.03	0.78	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16
3.3 V PCI-X	Per PCI-X spec	–	High	10	25 <sup>3</sup>	0.49	2.09	0.03	0.78	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16
3.3 V GTL	20 <sup>4</sup>	–	High	10	25	0.45	1.55	0.03	2.19	–	0.32	1.52	1.55	–	–	3.19	3.22
2.5 V GTL	20 <sup>4</sup>	–	High	10	25	0.45	1.59	0.03	1.83	–	0.32	1.61	1.59	–	–	3.28	3.26
3.3 V GTL+	35	–	High	10	25	0.45	1.53	0.03	1.19	–	0.32	1.56	1.53	–	–	3.23	3.20
2.5 V GTL+	33	–	High	10	25	0.45	1.65	0.03	1.13	–	0.32	1.68	1.57	–	–	3.35	3.24
HSTL (I)	8	–	High	20	50	0.49	2.37	0.03	1.59	–	0.32	2.42	2.35	–	–	4.09	4.02
HSTL (II)	15 <sup>4</sup>	–	High	20	25	0.49	2.26	0.03	1.59	–	0.32	2.30	2.03	–	–	3.97	3.70
SSTL2 (I)	15	–	High	30	50	0.49	1.59	0.03	1.00	–	0.32	1.62	1.38	–	–	3.29	3.05
SSTL2 (II)	18	–	High	30	25	0.49	1.62	0.03	1.00	–	0.32	1.65	1.32	–	–	3.32	2.99
SSTL3 (I)	14	–	High	30	50	0.49	1.72	0.03	0.93	–	0.32	1.75	1.37	–	–	3.42	3.04
SSTL3 (II)	21	–	High	30	25	0.49	1.54	0.03	0.93	–	0.32	1.57	1.25	–	–	3.24	2.92
LVDS/B-LVDS/M-LVDS	24	–	High	–	–	0.49	1.40	0.03	1.36	–	–	–	–	–	–	–	
LVPECL	24	–	High	–	–	0.49	1.36	0.03	1.22	–	–	–	–	–	–	–	

**Notes:**

1. The minimum drive strength for any LVC MOS 3.3 V software configuration when run in wide range is  $\pm 100 \mu\text{A}$ . Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. All LVC MOS 3.3 V software macros support LVC MOS 3.3V wide range as specified in the JESD8b specification.
3. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-11 on page 2-38 for connectivity. This resistor is not required during normal operation.
4. Output drive strength is below JEDEC specification.
5. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5.

## 1.8 V LVCMOS

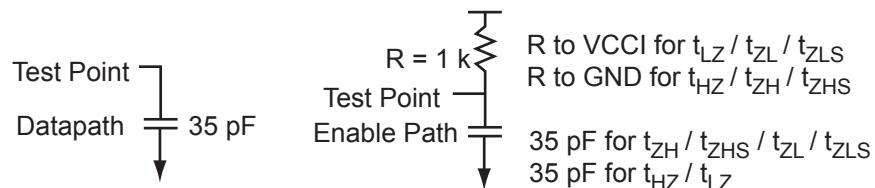
Low-Voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

**Table 2-37 • Minimum and Maximum DC Input and Output Levels**

1.8 V LVCMOS	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	µA <sup>4</sup>	µA <sup>4</sup>
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	2	2	11	9	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	4	4	22	17	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	6	6	44	35	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	8	8	51	45	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	12	12	74	91	10	10
16 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	16	16	74	91	10	10

**Notes:**

1. IIL is the input leakage current per I/O pin over recommended operation conditions where  $-0.3 \text{ V} < \text{VIN} < \text{VIL}$ .
2. IIH is the input leakage current per I/O pin over recommended operating conditions  $\text{VIH} < \text{VIN} < \text{VCCI}$ . Input current is larger when operating outside recommended ranges.
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.
5. Software default selection highlighted in gray.



**Figure 2-9 • AC Loading**

**Table 2-38 • AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	1.8	0.9	-	35

**Note:** \*Measuring point =  $V_{trip}$ . See [Table 2-15](#) on page 2-18 for a complete table of trip points.

## Timing Characteristics

**Table 2-80 • LVDS**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425 \text{ V}$ , Worst-Case  $V_{CCI} = 2.3 \text{ V}$

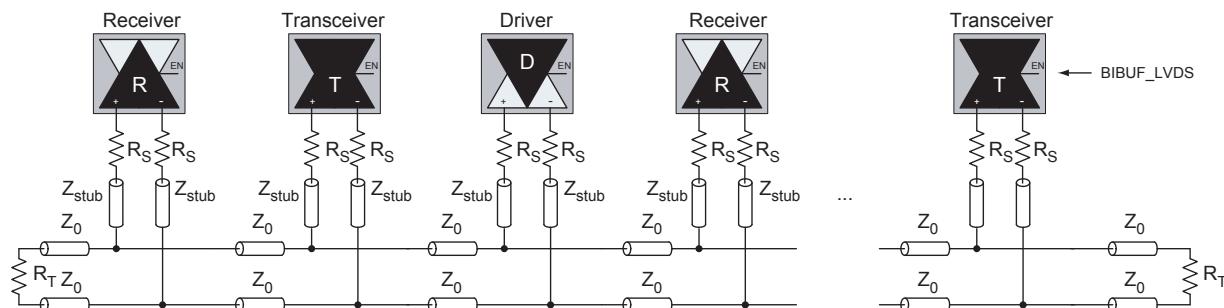
Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	Units
Std.	0.66	1.87	0.04	1.82	ns
-1	0.56	1.59	0.04	1.55	ns
-2	0.49	1.40	0.03	1.36	ns

**Note:** For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

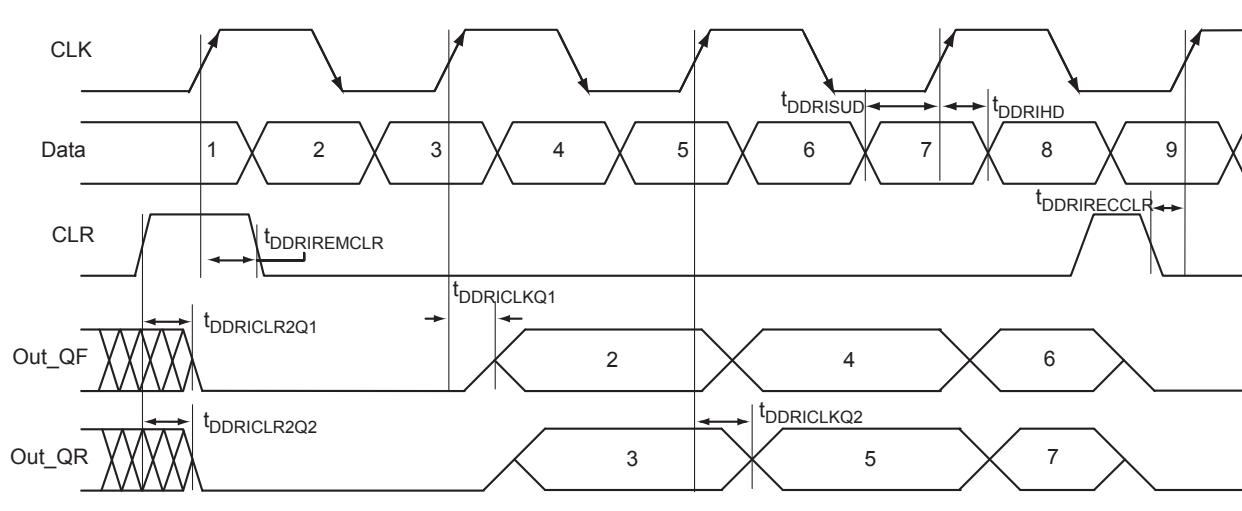
## B-LVDS/M-LVDS

Bus LVDS (B-LVDS) and Multipoint LVDS (M-LVDS) specifications extend the existing LVDS standard to high-performance multipoint bus applications. Multidrop and multipoint bus configurations may contain any combination of drivers, receivers, and transceivers. Microsemi LVDS drivers provide the higher drive current required by B-LVDS and M-LVDS to accommodate the loading. The drivers require series terminations for better signal quality and to control voltage swing. Termination is also required at both ends of the bus since the driver can be located anywhere on the bus. These configurations can be implemented using the TRIBUF\_LVDS and BIBUF\_LVDS macros along with appropriate terminations. Multipoint designs using Microsemi LVDS macros can achieve up to 200 MHz with a maximum of 20 loads. A sample application is given in [Figure 2-23](#). The input and output buffer delays are available in the LVDS section in [Table 2-80](#).

Example: For a bus consisting of 20 equidistant loads, the following terminations provide the required differential voltage, in worst-case Industrial operating conditions, at the farthest receiver:  $R_S = 60 \Omega$  and  $R_T = 70 \Omega$ , given  $Z_0 = 50 \Omega$  (2") and  $Z_{\text{stub}} = 50 \Omega$  (~1.5").



**Figure 2-23 • B-LVDS/M-LVDS Multipoint Application Using LVDS I/O Buffers**



**Figure 2-31 • Input DDR Timing Diagram**

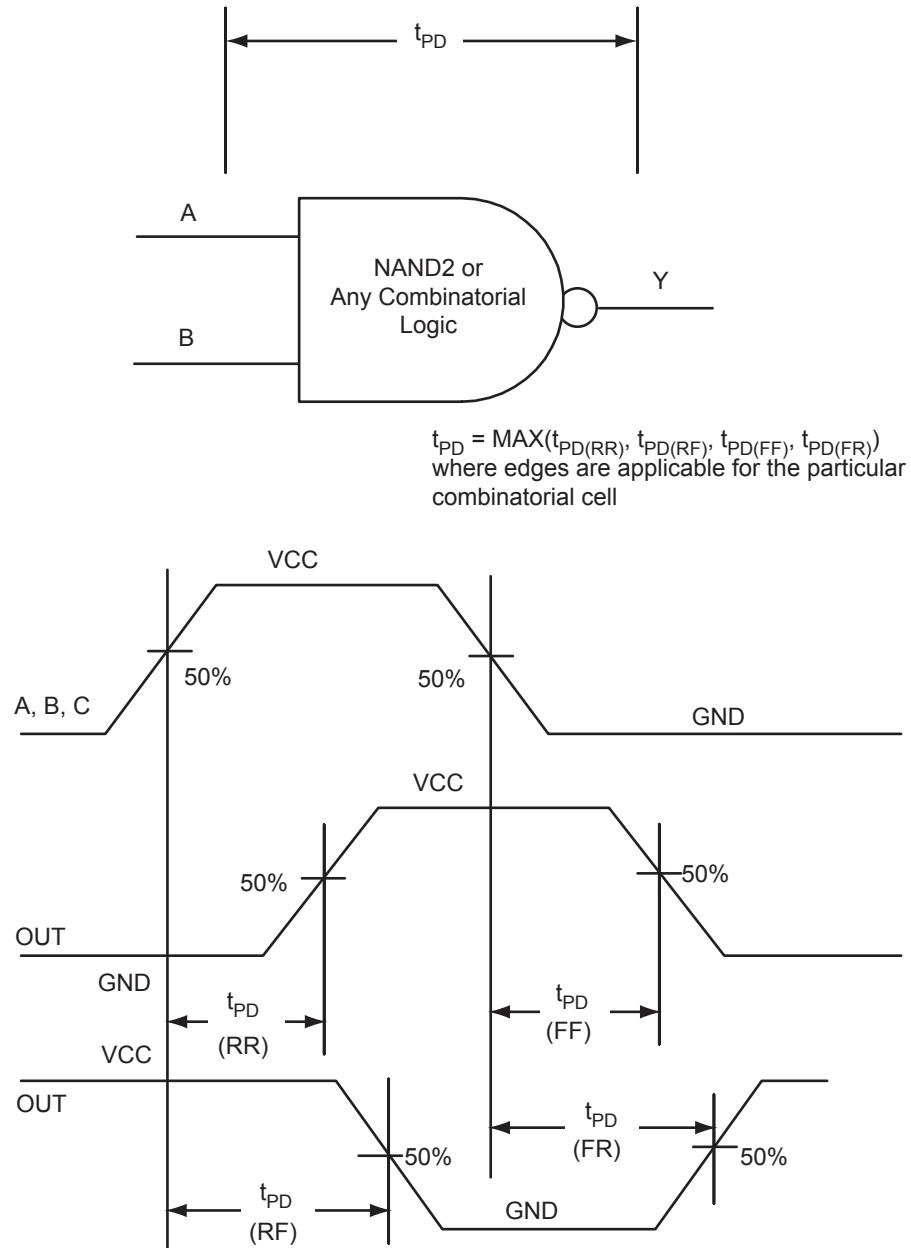
#### Timing Characteristics

**Table 2-90 • Input DDR Propagation Delays**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425 \text{ V}$

Parameter	Description	-2	-1	Std.	Units
$t_{DDRICLKQ1}$	Clock-to-Out Out_QR for Input DDR	0.39	0.44	0.52	ns
$t_{DDRICLKQ2}$	Clock-to-Out Out_QF for Input DDR	0.27	0.31	0.37	ns
$t_{DDDRISUD}$	Data Setup for Input DDR	0.28	0.32	0.38	ns
$t_{DDRIHD}$	Data Hold for Input DDR	0.00	0.00	0.00	ns
$t_{DDRICLQ1}$	Asynchronous Clear to Out Out_QR for Input DDR	0.57	0.65	0.76	ns
$t_{DDRICLQ2}$	Asynchronous Clear-to-Out Out_QF for Input DDR	0.46	0.53	0.62	ns
$t_{DDRIREMCLR}$	Asynchronous Clear Removal Time for Input DDR	0.00	0.00	0.00	ns
$t_{DDRIRECCLR}$	Asynchronous Clear Recovery Time for Input DDR	0.22	0.25	0.30	ns
$t_{DDRICKMPWHL}$	Asynchronous Clear Minimum Pulse Width for Input DDR	0.22	0.25	0.30	ns
$t_{DDRICKMPWL}$	Clock Minimum Pulse Width High for Input DDR	0.36	0.41	0.48	ns
$t_{DDRICKMPWL}$	Clock Minimum Pulse Width Low for Input DDR	0.32	0.37	0.43	ns
$F_{DDRIMAX}$	Maximum Frequency for Input DDR	1404	1232	1048	MHz

*Note:* For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.



**Figure 2-35 • Timing Model and Waveforms**

## Timing Characteristics

**Table 2-99 • RAM4K9**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V

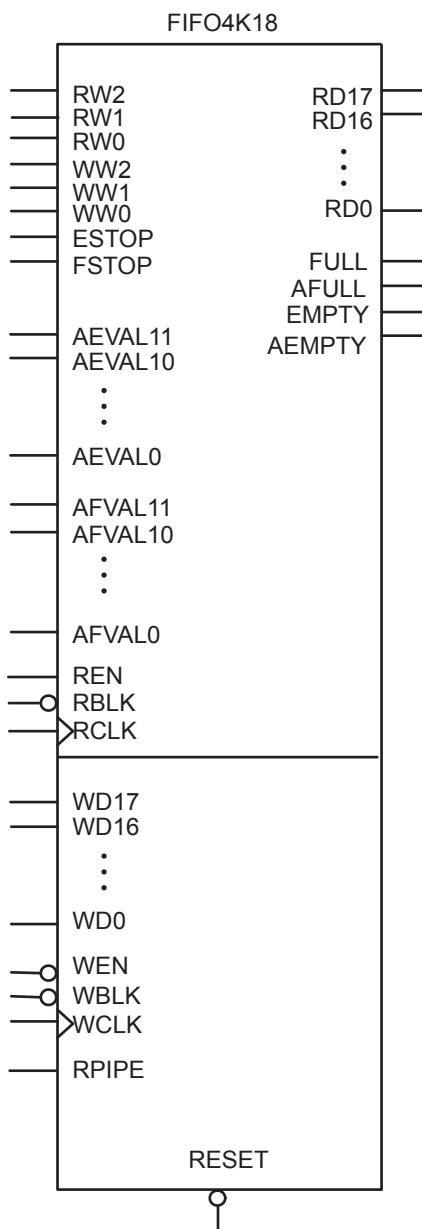
Parameter	Description	-2	-1	Std.	Units
$t_{AS}$	Address setup time	0.25	0.28	0.33	ns
$t_{AH}$	Address hold time	0.00	0.00	0.00	ns
$t_{ENS}$	REN, WEN setup time	0.14	0.16	0.19	ns
$t_{ENH}$	REN, WEN hold time	0.10	0.11	0.13	ns
$t_{BKS}$	BLK setup time	0.23	0.27	0.31	ns
$t_{BKH}$	BLK hold time	0.02	0.02	0.02	ns
$t_{DS}$	Input data (DIN) setup time	0.18	0.21	0.25	ns
$t_{DH}$	Input data (DIN) hold time	0.00	0.00	0.00	ns
$t_{CKQ1}$	Clock High to new data valid on DOUT (output retained, WMODE = 0)	1.79	2.03	2.39	ns
	Clock High to new data valid on DOUT (flow-through, WMODE = 1)	2.36	2.68	3.15	ns
$t_{CKQ2}$	Clock High to new data valid on DOUT (pipelined)	0.89	1.02	1.20	ns
$t_{C2CWWL}^1$	Address collision clk-to-clk delay for reliable write after write on same address—Applicable to Closing Edge	0.33	0.28	0.25	ns
$t_{C2CWWH}^1$	Address collision clk-to-clk delay for reliable write after write on same address—Applicable to Rising Edge	0.30	0.26	0.23	ns
$t_{C2CRWH}^1$	Address collision clk-to-clk delay for reliable read access after write on same address—Applicable to Opening Edge	0.45	0.38	0.34	ns
$t_{C2CWRH}^1$	Address collision clk-to-clk delay for reliable write access after read on same address—Applicable to Opening Edge	0.49	0.42	0.37	ns
$t_{RSTBQ}$	RESET Low to data out Low on DO (flow-through)	0.92	1.05	1.23	ns
	RESET Low to Data Out Low on DO (pipelined)	0.92	1.05	1.23	ns
$t_{REMRSTB}$	RESET removal	0.29	0.33	0.38	ns
$t_{RECRSTB}$	RESET recovery	1.50	1.71	2.01	ns
$t_{MPWRSTB}$	RESET minimum pulse width	0.21	0.24	0.29	ns
$t_{CYC}$	Clock cycle time	3.23	3.68	4.32	ns
$F_{MAX}$	Maximum frequency	310	272	231	MHz

**Notes:**

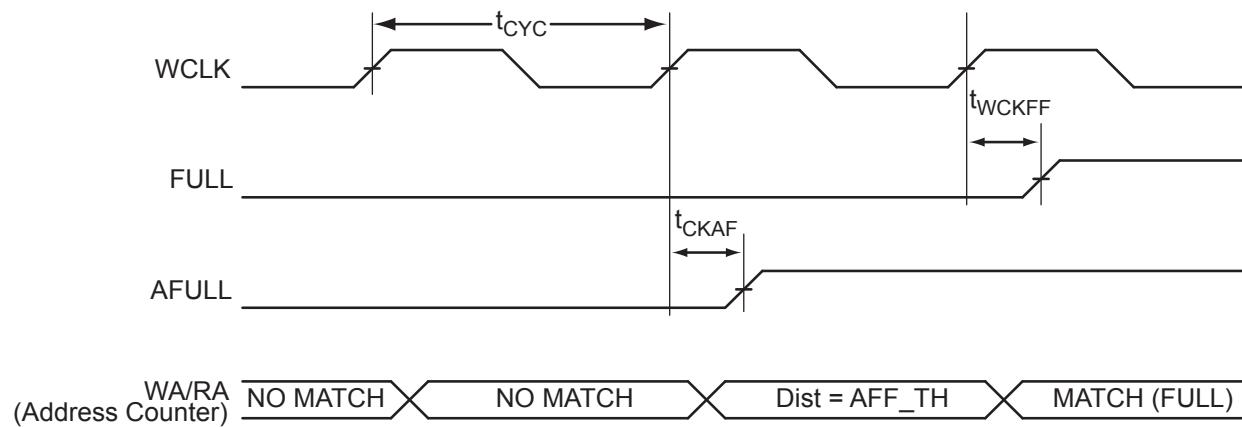
- For more information, refer to the application note *Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs*.
- For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

## FIFO

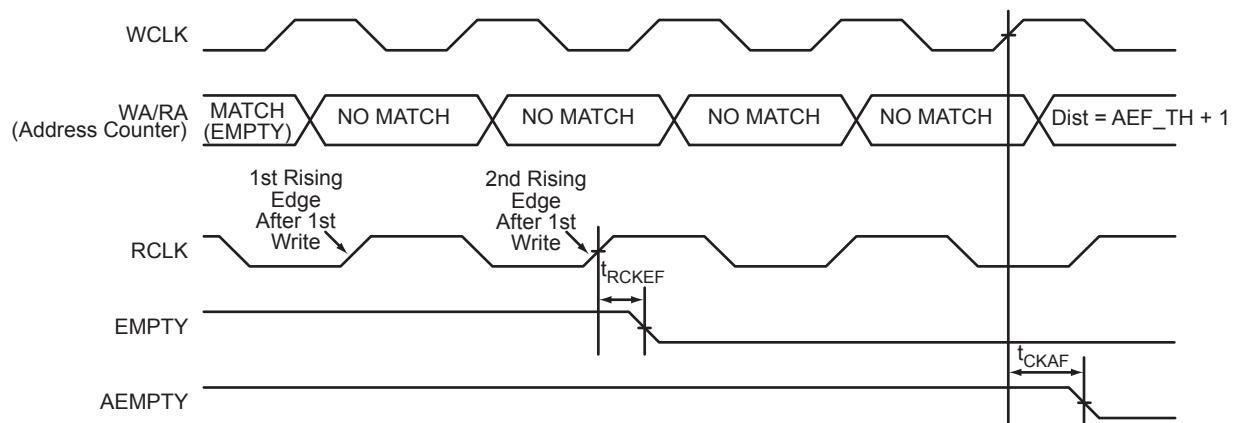
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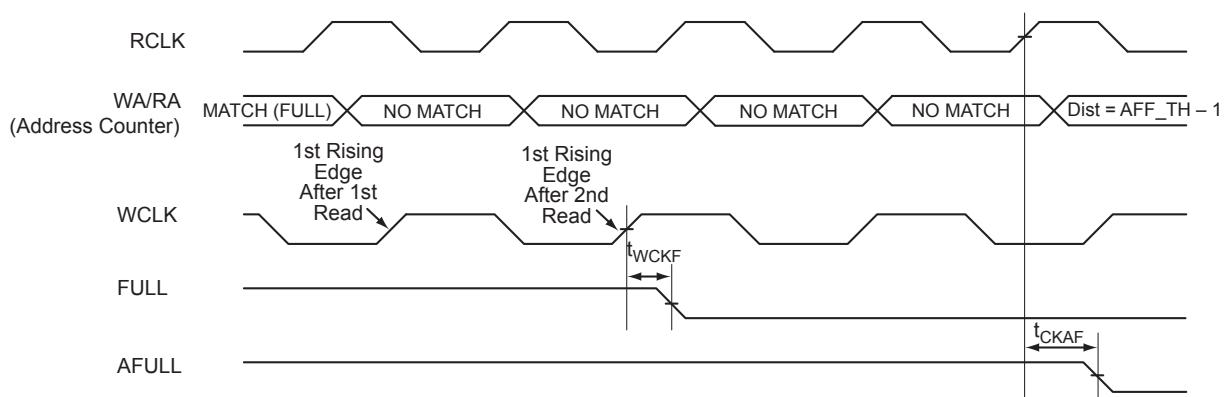
**Figure 2-46 • FIFO Model**



**Figure 2-51 • FIFO FULL Flag and AFULL Flag Assertion**



**Figure 2-52 • FIFO EMPTY Flag and AEMPTY Flag Deassertion**



**Figure 2-53 • FIFO FULL Flag and AFULL Flag Deassertion**

**VJTAG****JTAG Supply Voltage**

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND. It should be noted that VCC is required to be powered for JTAG operation; VJTAG alone is insufficient. If a device is in a JTAG chain of interconnected boards, the board containing the device can be powered down, provided both VJTAG and VCC to the part remain powered; otherwise, JTAG signals will not be able to transition the device, even in bypass mode.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

**VPUMP****Programming Supply Voltage**

For programming, VPUMP should be 3.3 V nominal. During normal device operation, VPUMP can be left floating or can be tied (pulled up) to any voltage between 0 V and the VPUMP maximum. Programming power supply voltage (VPUMP) range is listed in the datasheet.

When the VPUMP pin is tied to ground, it will shut off the charge pump circuitry, resulting in no sources of oscillation from the charge pump circuitry.

For proper programming, 0.01  $\mu$ F and 0.33  $\mu$ F capacitors (both rated at 16 V) are to be connected in parallel across VPUMP and GND, and positioned as close to the FPGA pins as possible.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

## User-Defined Supply Pins

**VREF****I/O Voltage Reference**

Reference voltage for I/O minibanks. VREF pins are configured by the user from regular I/Os, and any I/O in a bank, except JTAG I/Os, can be designated the voltage reference I/O. Only certain I/O standards require a voltage reference—HSTL (I) and (II), SSTL2 (I) and (II), SSTL3 (I) and (II), and GTL/GTL+. One VREF pin can support the number of I/Os available in its minibank.

## User Pins

**I/O****User Input/Output**

The I/O pin functions as an input, output, tristate, or bidirectional buffer. Input and output signal levels are compatible with the I/O standard selected.

During programming, I/Os become tristated and weakly pulled up to VCCI. With VCCI, VMV, and VCC supplies continuously powered up, when the device transitions from programming to operating mode, the I/Os are instantly configured to the desired user configuration.

Unused I/Os are configured as follows:

- Output buffer is disabled (with tristate value of high impedance)
- Input buffer is disabled (with tristate value of high impedance)
- Weak pull-up is programmed

**GL****Globals**

GL I/Os have access to certain clock conditioning circuitry (and the PLL) and/or have direct access to the global network (spines). Additionally, the global I/Os can be used as regular I/Os, since they have identical capabilities. Unused GL pins are configured as inputs with pull-up resistors.

See more detailed descriptions of global I/O connectivity in the "Clock Conditioning Circuits in Low Power Flash Devices and Mixed Signal FPGAs" chapter of the [ProASIC3E FPGA Fabric User's Guide](#). All inputs labeled GC/GF are direct inputs into the quadrant clocks. For example, if GAA0 is used for an input, GAA1 and GAA2 are no longer available for input to the quadrant globals. All inputs labeled GC/GF are direct inputs into the chip-level globals, and the rest are connected to the quadrant globals. The inputs to the global network are multiplexed, and only one input can be used as a global input.

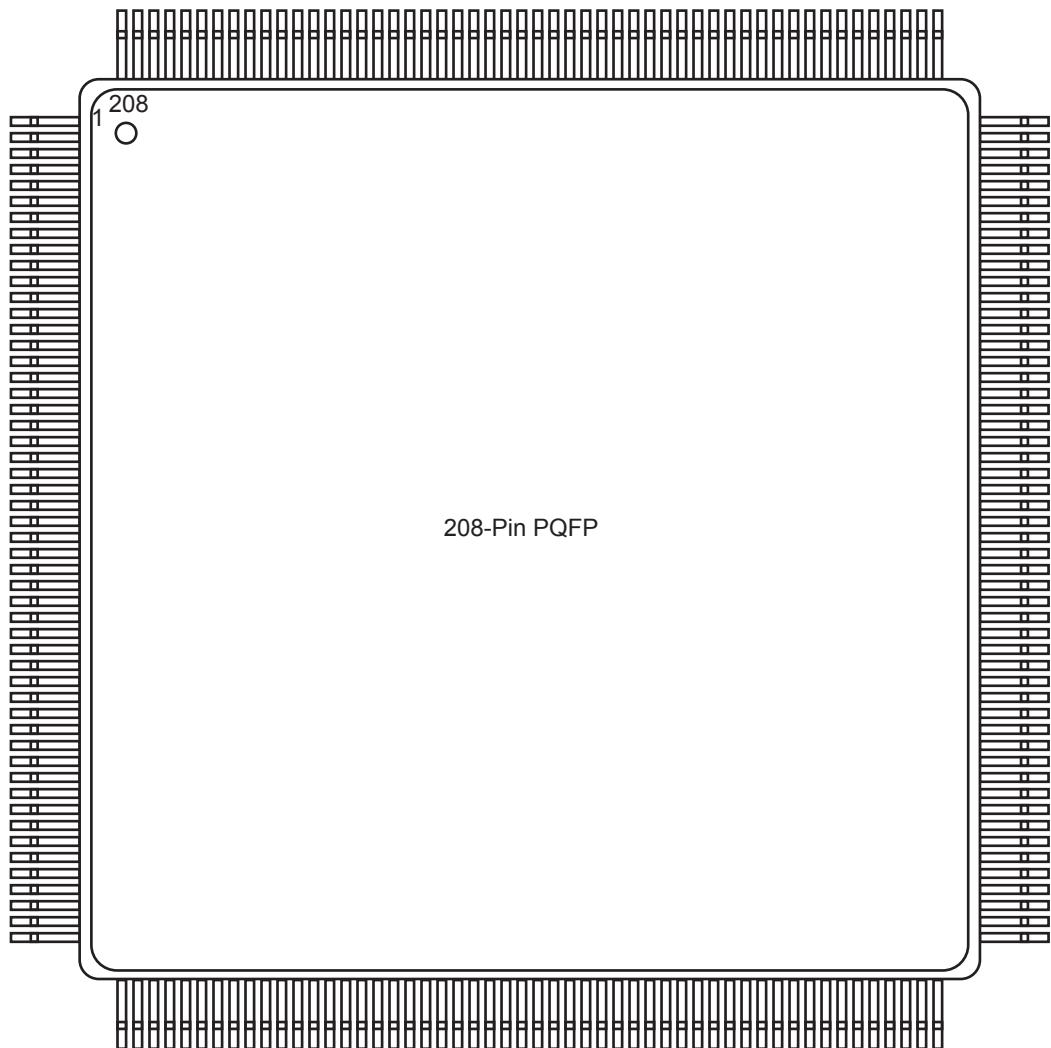
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## 4 – Package Pin Assignments

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### PQ208

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*Note:* This is the top view of the package.

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#### Note

For Package Manufacturing and Environmental information, visit the Resource Center at  
<http://www.microsemi.com/products/fpga-soc/solutions>.

<b>PQ208</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
1	GND
2	GNDQ
3	VMV7
4	GAB2/IO220PSB7V3
5	GAA2/IO221PDB7V3
6	IO221NDB7V3
7	GAC2/IO219PDB7V3
8	IO219NDB7V3
9	IO215PDB7V3
10	IO215NDB7V3
11	IO212PDB7V2
12	IO212NDB7V2
13	IO208PDB7V2
14	IO208NDB7V2
15	IO204PSB7V1
16	VCC
17	GND
18	VCCIB7
19	IO200PDB7V1
20	IO200NDB7V1
21	IO196PSB7V0
22	GFC1/IO192PSB7V0
23	GFB1/IO191PDB7V0
24	GFB0/IO191NDB7V0
25	VCOMPLF
26	GFA0/IO190NPB6V2
27	VCCPLF
28	GFA1/IO190PPB6V2
29	GND
30	GFA2/IO189PDB6V2
31	IO189NDB6V2
32	GFB2/IO188PPB6V2
33	GFC2/IO187PPB6V2
34	IO188NPB6V2
35	IO187NPB6V2
36	VCC

<b>PQ208</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
37	IO184PDB6V2
38	IO184NDB6V2
39	IO180PSB6V1
40	VCCIB6
41	GND
42	IO176PDB6V1
43	IO176NDB6V1
44	GEC1/IO169PDB6V0
45	GEC0/IO169NDB6V0
46	GEB1/IO168PPB6V0
47	GEA1/IO167PPB6V0
48	GEB0/IO168NPB6V0
49	GEA0/IO167NPB6V0
50	VMV6
51	GNDQ
52	GND
53	VMV5
54	GNDQ
55	IO166NDB5V3
56	GEA2/IO166PDB5V3
57	IO165NDB5V3
58	GEB2/IO165PDB5V3
59	IO164NDB5V3
60	GEC2/IO164PDB5V3
61	IO163PSB5V3
62	VCCIB5
63	IO161PSB5V3
64	IO157NDB5V2
65	GND
66	IO157PDB5V2
67	IO153NDB5V2
68	IO153PDB5V2
69	IO149NDB5V1
70	IO149PDB5V1
71	VCC
72	VCCIB5

<b>PQ208</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
73	IO145NDB5V1
74	IO145PDB5V1
75	IO143NDB5V1
76	IO143PDB5V1
77	IO137NDB5V0
78	IO137PDB5V0
79	IO135NDB5V0
80	IO135PDB5V0
81	GND
82	IO131NDB4V2
83	IO131PDB4V2
84	IO129NDB4V2
85	IO129PDB4V2
86	IO127NDB4V2
87	IO127PDB4V2
88	VCC
89	VCCIB4
90	IO121NDB4V1
91	IO121PDB4V1
92	IO119NDB4V1
93	IO119PDB4V1
94	IO113NDB4V0
95	GDC2/IO113PDB4V0
96	IO112NDB4V0
97	GND
98	GDB2/IO112PDB4V0
99	GDA2/IO111PSB4V0
100	GNDQ
101	TCK
102	TDI
103	TMS
104	VMV4
105	GND
106	VPUMP
107	GNDQ
108	TDO

<b>PQ208</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
118	IO134NDB3V2
119	IO134PDB3V2
120	IO132NDB3V2
121	IO132PDB3V2
122	GND
123	VCCIB3
124	GCC2/IO117PSB3V0
125	GCB2/IO116PSB3V0
126	NC
127	IO115NDB3V0
128	GCA2/IO115PDB3V0
129	GCA1/IO114PPB3V0
130	GND
131	VCCPLC
132	GCA0/IO114NPB3V0
133	VCOMPLC
134	GCB0/IO113NDB2V3
135	GCB1/IO113PDB2V3
136	GCC1/IO112PSB2V3
137	IO110NDB2V3
138	IO110PDB2V3
139	IO106PSB2V3
140	VCCIB2
141	GND
142	VCC
143	IO99NDB2V2
144	IO99PDB2V2
145	IO96NDB2V1
146	IO96PDB2V1
147	IO91NDB2V1
148	IO91PDB2V1
149	IO88NDB2V0
150	IO88PDB2V0
151	GBC2/IO84PSB2V0
152	GBA2/IO82PSB2V0
153	GBB2/IO83PSB2V0
154	VMV2
155	GNDQ
156	GND

<b>PQ208</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
157	VMV1
158	GNDQ
159	GBA1/IO81PDB1V4
160	GBA0/IO81NDB1V4
161	GBB1/IO80PDB1V4
162	GND
163	GBB0/IO80NDB1V4
164	GBC1/IO79PDB1V4
165	GBC0/IO79NDB1V4
166	IO74PDB1V4
167	IO74NDB1V4
168	IO70PDB1V3
169	IO70NDB1V3
170	VCCIB1
171	VCC
172	IO56PSB1V1
173	IO55PDB1V1
174	IO55NDB1V1
175	IO54PDB1V1
176	IO54NDB1V1
177	IO40PDB0V4
178	GND
179	IO40NDB0V4
180	IO37PDB0V4
181	IO37NDB0V4
182	IO35PDB0V4
183	IO35NDB0V4
184	IO32PDB0V3
185	IO32NDB0V3
186	VCCIB0
187	VCC
188	IO28PDB0V3
189	IO28NDB0V3
190	IO24PDB0V2
191	IO24NDB0V2
192	IO21PSB0V2
193	IO16PDB0V1
194	IO16NDB0V1
195	GND

<b>PQ208</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
196	IO11PDB0V1
197	IO11NDB0V1
198	IO08PDB0V0
199	IO08NDB0V0
200	VCCIB0
201	GAC1/IO02PDB0V0
202	GAC0/IO02NDB0V0
203	GAB1/IO01PDB0V0
204	GAB0/IO01NDB0V0
205	GAA1/IO00PDB0V0
206	GAA0/IO00NDB0V0
207	GNDQ
208	VMV0

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE600 Function</b>
H19	IO41PDB2V0
H20	VCC
H21	NC
H22	NC
J1	IO123NDB7V0
J2	IO123PDB7V0
J3	NC
J4	IO124PDB7V0
J5	IO125PDB7V0
J6	IO126PDB7V0
J7	IO130NDB7V1
J8	VCCIB7
J9	GND
J10	VCC
J11	VCC
J12	VCC
J13	VCC
J14	GND
J15	VCCIB2
J16	IO38NDB2V0
J17	IO40NDB2V0
J18	IO40PDB2V0
J19	IO45PPB2V1
J20	NC
J21	IO48PDB2V1
J22	IO46PDB2V1
K1	IO121NDB7V0
K2	IO121PDB7V0
K3	NC
K4	IO124NDB7V0
K5	IO125NDB7V0
K6	IO126NDB7V0
K7	GFC1/IO120PPB7V0
K8	VCCIB7
K9	VCC
K10	GND

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE600 Function</b>
K11	GND
K12	GND
K13	GND
K14	VCC
K15	VCCIB2
K16	GCC1/IO50PPB2V1
K17	IO44NDB2V1
K18	IO44PDB2V1
K19	IO49NPB2V1
K20	IO45NPB2V1
K21	IO48NDB2V1
K22	IO46NDB2V1
L1	NC
L2	IO122PDB7V0
L3	IO122NDB7V0
L4	GFB0/IO119NPB7V0
L5	GFA0/IO118NDB6V1
L6	GFB1/IO119PPB7V0
L7	VCOMPLF
L8	GFC0/IO120NPB7V0
L9	VCC
L10	GND
L11	GND
L12	GND
L13	GND
L14	VCC
L15	GCC0/IO50NPB2V1
L16	GCB1/IO51PPB2V1
L17	GCA0/IO52NPB3V0
L18	VCOMPLC
L19	GCB0/IO51NPB2V1
L20	IO49PPB2V1
L21	IO47NDB2V1
L22	IO47PDB2V1
M1	NC
M2	IO114NPB6V1

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE600 Function</b>
M3	IO117NDB6V1
M4	GFA2/IO117PDB6V1
M5	GFA1/IO118PDB6V1
M6	VCCPLF
M7	IO116NDB6V1
M8	GFB2/IO116PDB6V1
M9	VCC
M10	GND
M11	GND
M12	GND
M13	GND
M14	VCC
M15	GCB2/IO54PPB3V0
M16	GCA1/IO52PPB3V0
M17	GCC2/IO55PPB3V0
M18	VCCPLC
M19	GCA2/IO53PDB3V0
M20	IO53NDB3V0
M21	IO56PDB3V0
M22	NC
N1	IO114PPB6V1
N2	IO111NDB6V1
N3	NC
N4	GFC2/IO115PPB6V1
N5	IO113PPB6V1
N6	IO112PDB6V1
N7	IO112NDB6V1
N8	VCCIB6
N9	VCC
N10	GND
N11	GND
N12	GND
N13	GND
N14	VCC
N15	VCCIB3
N16	IO54NPB3V0

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
N17	IO91NPB3V0
N18	IO90NPB3V0
N19	IO91PPB3V0
N20	GNDQ
N21	IO93NDB3V0
N22	IO95PDB3V1
P1	NC
P2	IO183PDB6V2
P3	IO187NPB6V2
P4	IO184NPB6V2
P5	IO176PPB6V1
P6	IO182PDB6V1
P7	IO182NDB6V1
P8	VCCIB6
P9	GND
P10	VCC
P11	VCC
P12	VCC
P13	VCC
P14	GND
P15	VCCIB3
P16	GDB0/IO109NPB3V2
P17	IO97NDB3V1
P18	IO97PDB3V1
P19	IO99PDB3V1
P20	VMV3
P21	IO98PDB3V1
P22	IO95NDB3V1
R1	NC
R2	IO177PDB6V1
R3	VCC
R4	IO176NPB6V1
R5	IO174NDB6V0
R6	IO174PDB6V0
R7	GEC0/IO169NPB6V0
R8	VMV5

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
R9	VCCIB5
R10	VCCIB5
R11	IO135NDB5V0
R12	IO135PDB5V0
R13	VCCIB4
R14	VCCIB4
R15	VMV3
R16	VCCPLD
R17	GDB1/IO109PPB3V2
R18	GDC1/IO108PDB3V2
R19	IO99NDB3V1
R20	VCC
R21	IO98NDB3V1
R22	IO101PDB3V1
T1	NC
T2	IO177NDB6V1
T3	NC
T4	IO171PDB6V0
T5	IO171NDB6V0
T6	GEC1/IO169PPB6V0
T7	VCOMPLE
T8	GNDQ
T9	GEA2/IO166PPB5V3
T10	IO145NDB5V1
T11	IO141NDB5V0
T12	IO139NDB5V0
T13	IO119NDB4V1
T14	IO119PDB4V1
T15	GNDQ
T16	VCOMPLD
T17	VJTAG
T18	GDC0/IO108NDB3V2
T19	GDA1/IO110PDB3V2
T20	NC
T21	IO103PDB3V2
T22	IO101NDB3V1

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
U1	IO175PPB6V1
U2	IO173PDB6V0
U3	IO173NDB6V0
U4	GEB1/IO168PDB6V0
U5	GEB0/IO168NDB6V0
U6	VMV6
U7	VCCPLE
U8	IO166NPB5V3
U9	IO157PPB5V2
U10	IO145PDB5V1
U11	IO141PDB5V0
U12	IO139PDB5V0
U13	IO121NDB4V1
U14	IO121PDB4V1
U15	VMV4
U16	TCK
U17	VPUMP
U18	TRST
U19	GDA0/IO110NDB3V2
U20	NC
U21	IO103NDB3V2
U22	IO105PDB3V2
V1	NC
V2	IO175NPB6V1
V3	GND
V4	GEA1/IO167PDB6V0
V5	GEA0/IO167NDB6V0
V6	GNDQ
V7	GEC2/IO164PDB5V3
V8	IO157NPB5V2
V9	IO151NDB5V2
V10	IO151PDB5V2
V11	IO137NDB5V0
V12	IO137PDB5V0
V13	IO123NDB4V1
V14	IO123PDB4V1

FG484		FG484		FG484	
Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function
H19	IO100PDB2V2	K11	GND	M3	IO272NDB6V4
H20	VCC	K12	GND	M4	GFA2/IO272PDB6V4
H21	VMV2	K13	GND	M5	GFA1/IO273PDB6V4
H22	IO105PDB2V2	K14	VCC	M6	VCCPLF
J1	IO285NDB7V1	K15	VCCIB2	M7	IO271NDB6V4
J2	IO285PDB7V1	K16	GCC1/IO112PPB2V3	M8	GFB2/IO271PDB6V4
J3	VMV7	K17	IO108NDB2V3	M9	VCC
J4	IO279PDB7V0	K18	IO108PDB2V3	M10	GND
J5	IO283PDB7V1	K19	IO110NPB2V3	M11	GND
J6	IO281PDB7V0	K20	IO106NPB2V3	M12	GND
J7	IO287NDB7V1	K21	IO109NDB2V3	M13	GND
J8	VCCIB7	K22	IO107NDB2V3	M14	VCC
J9	GND	L1	IO257PSB6V2	M15	GCB2/IO116PPB3V0
J10	VCC	L2	IO276PDB7V0	M16	GCA1/IO114PPB3V0
J11	VCC	L3	IO276NDB7V0	M17	GCC2/IO117PPB3V0
J12	VCC	L4	GFB0/IO274NPB7V0	M18	VCCPLC
J13	VCC	L5	GFA0/IO273NDB6V4	M19	GCA2/IO115PDB3V0
J14	GND	L6	GFB1/IO274PPB7V0	M20	IO115NDB3V0
J15	VCCIB2	L7	VCOMPLF	M21	IO126PDB3V1
J16	IO84NDB2V0	L8	GFC0/IO275NPB7V0	M22	IO124PSB3V1
J17	IO104NDB2V2	L9	VCC	N1	IO255PPB6V2
J18	IO104PDB2V2	L10	GND	N2	IO253NDB6V2
J19	IO106PPB2V3	L11	GND	N3	VMV6
J20	GNDQ	L12	GND	N4	GFC2/IO270PPB6V4
J21	IO109PDB2V3	L13	GND	N5	IO261PPB6V3
J22	IO107PDB2V3	L14	VCC	N6	IO263PDB6V3
K1	IO277NDB7V0	L15	GCC0/IO112NPB2V3	N7	IO263NDB6V3
K2	IO277PDB7V0	L16	GCB1/IO113PPB2V3	N8	VCCIB6
K3	GNDQ	L17	GCA0/IO114NPB3V0	N9	VCC
K4	IO279NDB7V0	L18	VCOMPLC	N10	GND
K5	IO283NDB7V1	L19	GCB0/IO113NPB2V3	N11	GND
K6	IO281NDB7V0	L20	IO110PPB2V3	N12	GND
K7	GFC1/IO275PPB7V0	L21	IO111NDB2V3	N13	GND
K8	VCCIB7	L22	IO111PDB2V3	N14	VCC
K9	VCC	M1	GNDQ	N15	VCCIB3
K10	GND	M2	IO255NPB6V2	N16	IO116NPB3V0

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
A1	GND
A2	GND
A3	GAA0/IO00NDB0V0
A4	GAA1/IO00PDB0V0
A5	IO06NDB0V0
A6	IO09NDB0V1
A7	IO09PDB0V1
A8	IO14NDB0V1
A9	IO14PDB0V1
A10	IO22NDB0V2
A11	IO22PDB0V2
A12	IO26NDB0V3
A13	IO26PDB0V3
A14	IO30NDB0V3
A15	IO30PDB0V3
A16	IO34NDB1V0
A17	IO34PDB1V0
A18	IO38NDB1V0
A19	IO38PDB1V0
A20	IO41PDB1V1
A21	IO44PDB1V1
A22	IO49PDB1V2
A23	IO50PDB1V2
A24	GBC1/IO55PDB1V3
A25	GND
A26	GND
AA1	IO174PDB6V0
AA2	IO171PDB6V0
AA3	GEA1/IO167PPB6V0
AA4	GEC0/IO169NPB6V0
AA5	VCOMPLE
AA6	GND
AA7	IO165NDB5V3
AA8	GEB2/IO165PDB5V3
AA9	IO163PDB5V3
AA10	IO159NDB5V3

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
AA11	IO153NDB5V2
AA12	IO147NDB5V1
AA13	IO139NDB5V0
AA14	IO137NDB5V0
AA15	IO123NDB4V1
AA16	IO123PDB4V1
AA17	IO117NDB4V0
AA18	IO117PDB4V0
AA19	GDB2/IO112PDB4V0
AA20	GNDQ
AA21	TDO
AA22	GND
AA23	GND
AA24	IO102NDB3V1
AA25	IO102PDB3V1
AA26	IO98NDB3V1
AB1	IO174NDB6V0
AB2	IO171NDB6V0
AB3	GEB1/IO168PPB6V0
AB4	GEA0/IO167NPB6V0
AB5	VCCPLE
AB6	GND
AB7	GND
AB8	IO156NDB5V2
AB9	IO156PDB5V2
AB10	IO150PDB5V1
AB11	IO155PDB5V2
AB12	IO142PDB5V0
AB13	IO135NDB5V0
AB14	IO135PDB5V0
AB15	IO132PDB4V2
AB16	IO129PDB4V2
AB17	IO121PDB4V1
AB18	IO119NDB4V1
AB19	IO112NDB4V0
AB20	VMV4

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
AB21	TCK
AB22	TRST
AB23	GDC0/IO108NDB3V2
AB24	GDC1/IO108PDB3V2
AB25	IO104NDB3V2
AB26	IO104PDB3V2
AC1	IO170PDB6V0
AC2	GEB0/IO168NPB6V0
AC3	IO166NPB5V3
AC4	GNDQ
AC5	GND
AC6	IO160PDB5V3
AC7	IO161PDB5V3
AC8	IO154PDB5V2
AC9	GND
AC10	IO150NDB5V1
AC11	IO155NDB5V2
AC12	IO142NDB5V0
AC13	IO138NDB5V0
AC14	IO138PDB5V0
AC15	IO132NDB4V2
AC16	IO129NDB4V2
AC17	IO121NDB4V1
AC18	IO119PDB4V1
AC19	IO118NDB4V0
AC20	IO118PDB4V0
AC21	IO114PPB4V0
AC22	TMS
AC23	VJTAG
AC24	VMV3
AC25	IO106NDB3V2
AC26	IO106PDB3V2
AD1	IO170NDB6V0
AD2	GEA2/IO166PPB5V3
AD3	VMV5
AD4	GEC2/IO164PDB5V3

<b>FG896</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
A2	GND
A3	GND
A4	IO14NPB0V1
A5	GND
A6	IO07NPB0V0
A7	GND
A8	IO09NDB0V1
A9	IO17NDB0V2
A10	IO17PDB0V2
A11	IO21NDB0V2
A12	IO21PDB0V2
A13	IO33NDB0V4
A14	IO33PDB0V4
A15	IO35NDB0V4
A16	IO35PDB0V4
A17	IO41NDB1V0
A18	IO43NDB1V0
A19	IO43PDB1V0
A20	IO45NDB1V0
A21	IO45PDB1V0
A22	IO57NDB1V2
A23	IO57PDB1V2
A24	GND
A25	IO69PPB1V3
A26	GND
A27	GBC1/IO79PPB1V4
A28	GND
A29	GND
AA1	IO256PDB6V2
AA2	IO248PDB6V1
AA3	IO248NDB6V1
AA4	IO246NDB6V1
AA5	GEA1/IO234PDB6V0
AA6	GEA0/IO234NDB6V0
AA7	IO243PPB6V1
AA8	IO245NDB6V1

<b>FG896</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
AA9	GEB1/IO235PPB6V0
AA10	VCC
AA11	IO226PPB5V4
AA12	VCCIB5
AA13	VCCIB5
AA14	VCCIB5
AA15	VCCIB5
AA16	VCCIB4
AA17	VCCIB4
AA18	VCCIB4
AA19	VCCIB4
AA20	IO174PDB4V2
AA21	VCC
AA22	IO142NPB3V3
AA23	IO144NDB3V3
AA24	IO144PDB3V3
AA25	IO146NDB3V4
AA26	IO146PDB3V4
AA27	IO147PDB3V4
AA28	IO139NDB3V3
AA29	IO139PDB3V3
AA30	IO133NDB3V2
AB1	IO256NDB6V2
AB2	IO244PDB6V1
AB3	IO244NDB6V1
AB4	IO241PDB6V0
AB5	IO241NDB6V0
AB6	IO243NPB6V1
AB7	VCCIB6
AB8	VCCPLE
AB9	VCC
AB10	IO222PDB5V3
AB11	IO218PPB5V3
AB12	IO206NDB5V1
AB13	IO206PDB5V1
AB14	IO198NDB5V0

<b>FG896</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
AB15	IO198PDB5V0
AB16	IO192NDB4V4
AB17	IO192PDB4V4
AB18	IO178NDB4V3
AB19	IO178PDB4V3
AB20	IO174NDB4V2
AB21	IO162NPB4V1
AB22	VCC
AB23	VCCPLD
AB24	VCCIB3
AB25	IO150PDB3V4
AB26	IO148PDB3V4
AB27	IO147NDB3V4
AB28	IO145PDB3V3
AB29	IO143PDB3V3
AB30	IO137PDB3V2
AC1	IO254PDB6V2
AC2	IO254NDB6V2
AC3	IO240PDB6V0
AC4	GEC1/IO236PDB6V0
AC5	IO237PDB6V0
AC6	IO237NDB6V0
AC7	VCOMPLE
AC8	GND
AC9	IO226NPB5V4
AC10	IO222NDB5V3
AC11	IO216NPB5V2
AC12	IO210NPB5V2
AC13	IO204NDB5V1
AC14	IO204PDB5V1
AC15	IO194NDB5V0
AC16	IO188NDB4V4
AC17	IO188PDB4V4
AC18	IO182PPB4V3
AC19	IO170NPB4V2
AC20	IO164NDB4V1